

# 目錄

審定書	
授權書	
中文摘要	I
英文摘要	III
謝誌	V
目錄	VII
Scheme 目錄	X
Table 目錄	X
Figure 目錄	X I
附圖目錄	X IV
第一章 緒論	1
1.1 有機電激發光簡介	1
1.1.1 有機電激發光的起源	1
1.1.2 電激發光原理與高分子發光二極體	3
1.1.2.1 電激發光原理	3
1.1.2.2 電極的選擇	7
1.1.2.2.1 陽極 (Anode)	7
1.1.2.2.2 陰極 (Cathode)	7
1.1.2.3 發光層 (Emitting layer , EML)	11
1.1.2.3.1 主發光體	11
1.1.2.3.2 客發光體材料	12
1.1.2.3.3 電子傳導層	12
1.1.2.3.4 電洞傳導層 (hole transporting layer , HTL)	13
1.1.2.4 能階理論	13

1.1.2.5 雙層與多層結構之元件介紹-----	15
1.1.2.6 高分子發光二極體材料簡介-----	17
1.2 文獻回顧-----	19
1.2.1 常用於 PLED 的電洞傳輸層-----	19
1.2.2 含硫、氮共軛高分子材料的發展-----	19
1.2.3 與 ITO 鍵結之電洞傳輸層-----	22
1.3 苯硫胺聚合物於 PLED 之應用-----	23
1.3.1 OLED 製程中真空蒸鍍與旋轉塗佈之比較-----	23
1.3.2 苯硫胺聚合物於 PLED 之優勢-----	24
1.4 研究動機與分子設計-----	25
1.4.1 研究動機-----	25
1.4.2 聚苯硫胺衍生物分子設計-----	26
第二章 實驗部份-----	27
2.1 試藥-----	27
2.2 測試儀器-----	27
2.2.1 核磁共振光譜儀( Nuclear Magnetic Resonance , NMR )-----	27
2.2.2 微差掃描卡計( Differential Scanning Calorimeter , DSC )-----	28
2.2.3 熱重分析儀( Thermal Gravimetric Analyzer , TGA )-----	28
2.2.4 凝膠滲透層析儀( Gel Permeation Chromatography , GPC )-----	28
2.2.5 紫外線與可見光譜儀 ( UV-Vis Spectrophotometer )-----	28
2.2.6 螢光光譜儀 ( Luminescence Spectrophotometer )-----	29
2.2.7 循環伏安計量儀( Cyclic Voltammetry , CV )-----	29
2.2.8 薄膜測厚儀( Surface Profile , $\alpha$ -step )-----	29
2.2.9 LED 元件性質的量測-----	29
2.2.10 半導體特性分析儀( Semiconductor Analyzer)-----	29
2.3 合成部份-----	30
2.3.1 單體 M1~M4 的合成-----	30

2.3.2 高分子 P1~P4 的合成-----	30
2.3.2.1 強酸誘導縮合聚合反應-----	35
第三章 結果與討論-----	45
3.1 單體 M1~M4 的合成物鑑定-----	45
3.2 聚合物 P1~P4 的合成物鑑定-----	45
3.2.1 聚合物 P1~P4 的 FT-IR 光譜-----	45
3.2.2 聚合物 P1~P4 的分子量分佈-----	46
3.3 聚合物 P1~P4 的熱性質分析-----	47
3.4 光學性質分析-----	49
3.5 電化學性質分析-----	49
3.5.1 循環伏安計量(Cyclic voltammetry)分析-----	49
3.5.2 HOMO 與 LUMO 能帶計算-----	50
3.6 有機發光二極體元件製作與光電性質量測-----	54
3.6.1 ITO pattern 的製作-----	54
3.6.2 元件的製備-----	55
3.6.3 P1 元件結構與光電性質-----	55
3.6.4 P2 元件結構與光電性質-----	59
3.6.5 P3 元件結構與光電性質-----	61
3.6.6 P4 元件結構與光電性質-----	64
3.6.7 紅光發光層元件結構與光電性質-----	67
3.6.8 摻雜 CSA 元件的改良-----	69
3.6.9 藍光元件結構與光電性質-----	71
3.6.10 加入 PEDOT 元件的結構與光電性質-----	73
3.7 薄膜導電度量測-----	76
3.7.1 待測薄膜的製作-----	76
3.7.2 測量薄膜導電度-----	76

第四章 結論	78
第五章 參考文獻	80

## List of Schemes

Scheme 1	Synthesis of M 1	39
Scheme 2	Synthesis of M 2	40
Scheme 3	Synthesis of M 3 and M 4	41
Scheme 4	Synthesis of P 1 and P 2	42
Scheme 5	Synthesis of P 3	43
Scheme 6	Synthesis of P 4	44



## List of tables

Table 1.1	The work function of electrodes	9
Table 1.1	Dependence of emission efficiency on electron injecting electrodes of PPV devices	9
Table 2.1	Molecular weights of PPSA samples obtained by GPC	36
Table 3.1	Molecular weight and polydispersity of polymers P1~P4	47
Table 3.2	Thermal transitions and thermal degradation temperatures of polymers P1~P4	48
Table 3.3	Energy level of polymers P1~P4	51
Table 3.4	Steps of Glass-cleaning process	54
Table 3.5	Devices P1a~P1c 的元件性質	57
Table 3.6	Devices P2a~P2c 的元件性質	59

Table 3.7	Devices P3a~P3c 的元件性質	62
Table 3.8	Devices P4a~P4c 的元件性質	65
Table 3.9	PFR Device 的元件性質	67
Table 3.10	改良 PFR Device 的元件性質	69
Table 3.11	PFB Device 的元件性質	71
Table 3.12	Devices P1pg~P4pb 的元件性質	73
Table 3.13	P1~P4 的表面導電度	76

## List of Figures

Fig. 1-1	Schematic of the EL device	2
Fig. 1-2	The structures of PVK and PPV	3
Fig. 1-3	The diagram of energy transfer	5
Fig. 1-4	The structure of single-layer type OLED device	5
Fig. 1-5	Band diagram of excitation formation in EL	6
Fig. 1-6	Energy diagram of ecitation formation in EL	6
Fig. 1-7.	含 ETL 之 OLEDs 元件構造與能量圖	7
Fig. 1-8	Schematic energy-level diagram for an ITO/PPV/Al device	8
Fig. 1-9	Energy diagram near the Ca/Organic layer interface depicting the excitons dissociation process in the presence of gap states	10
Fig. 1-10	主發光體材料	11
Fig. 1-11	客發光體材料	12
Fig. 1-12	常見的電子傳輸層	12
Fig. 1-13	常見的電洞傳輸層材料	13
Fig. 1-14	能階理論	14
Fig. 1-15	Structures of double-layer-type OLED device	16

Fig. 1-16	Structures of triple-layer-type OLED device-----	16
Fig. 1-17	PPV derivatives and their emission color range-----	17
Fig. 1-18	Poly(alkylthiophene) derivatives and their emission color range---	18
Fig. 1-19	Examples of blue-emitting materials-----	18
Fig. 1-20	Structure of PEDOT : PSS-----	19
Fig. 1-21	Structures of PPSA derivatives-----	20
Fig. 1-22	Structures of PPSA derivatives P1 ~ P8 -----	25
Fig. 1-23	Structures of the TPD-Si <sub>2</sub> precursor and crosslinked TPD-Si <sub>2</sub> -----	25
Fig. 2-1	The mechanism of acid-induced condensation reaction-----	41
Fig. 3-1	The FT-IR spectra of P1 ~ P4-----	46
Fig. 3-2	UV-Vis spectra of P1 ~ P4-----	49
Fig. 3-3	Energy level diagram of P1 ~ P4-----	51
Fig. 3-4	Cyclic voltammogram of the oxidation and energy band diagram of P1-----	52
Fig. 3-5	Cyclic voltammogram of the oxidation and energy band diagram of P2-----	52
Fig. 3-6	Cyclic voltammogram of the oxidation and energy band diagram of P3-----	53
Fig. 3-7	Cyclic voltammogram of the oxidation and energy band diagram of P4-----	53
Fig. 3-8	Structure of green electroluminescent material PPV1-----	55
Fig. 3-9	Energy level of Device P1b-----	56
Fig. 3-10	Luminance-Voltage and Yield-Voltage characteristics for the Devices P1a~P1c-----	58
Fig. 3-11	Current Density-Voltage characteristics for the Devices P1a~P1c -----	58
Fig. 3-12	Energy level of Device P2-----	60
Fig. 3-13	Luminance-Voltage and Yield-Voltage characteristics for the Devices P2a and P2c-----	58

Fig. 3-14	Current Density-Voltage characteristics for the Devices P1a, P1c, P2a and P2c-----	58
Fig. 3-15	Energy level of Device P3-----	60
Fig. 3-16	Luminance-Voltage and Yield-Voltage characteristics for the Devices P3a and P3c-----	58
Fig. 3-17	Current Density-Voltage characteristics for the Devices P3a and P3c-----	58
Fig. 3-18	Energy level of Device P4-----	60
Fig. 3-19	Luminance-Voltage and Yield-Voltage characteristics for the Devices P4a and P4c-----	58
Fig. 3-20	Current Density-Voltage characteristics for the Devices P4a and P4c-----	58
Fig. 3-21	Structure of red electroluminescent material PFR-----	67
Fig. 3-22	Luminance-Voltage characteristics for the Devices P1r~P4r-----	68
Fig. 3-23	Yield-Voltage characteristics for the Devices P1r~P4r-----	68
Fig. 3-24	Luminance-Voltage characteristics for the Devices P1r~P4ro-----	70
Fig. 3-25	Yield-Voltage characteristics for the Devices P1r~P4ro-----	70
Fig. 3-26	Structure of blue electroluminescent material PFB-----	71
Fig. 3-27	Luminance-Voltage characteristics for the Devices P1y~P4y-----	72
Fig. 3-28	Yield-Voltage characteristics for the Devices P1y~P4y-----	72
Fig. 3-29	Luminance-Voltage and Yield-Voltage characteristics for the Green Devices P1pg, P4pg, and PEDOT-----	74
Fig. 3-30	Luminance-Voltage and Yield-Voltage characteristics for the Red Devices P1pr, P4pr, and PEDOT-----	75
Fig. 3-31	Luminance-Voltage and Yield-Voltage characteristics for the Blue Devices P1pb, P4pb, and PEDOT-----	75

Fig. 3-32	Current-Voltage characteristics of Devices P1a, P1c, P2c, P3c and P4c, and PEDOT-----	77
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## List of 附圖

附圖.1	$^1\text{H}$ -NMR spectrum of M1-----	85
附圖.2	$^{13}\text{C}$ -NMR spectrum of M1-----	86
附圖.3	$^1\text{H}$ -NMR spectrum of M2-----	87
附圖.4	$^{13}\text{C}$ -NMR spectrum of M2-----	88
附圖.5	$^1\text{H}$ -NMR spectrum of M3-----	89
附圖.6	$^{13}\text{C}$ -NMR spectrum of M3-----	90
附圖.7	$^1\text{H}$ -NMR spectrum of M4-----	91
附圖.8	$^{13}\text{C}$ -NMR spectrum of M4-----	92
附圖.9	Mass spectrum of M1-----	93
附圖.10	Mass spectrum of M2-----	94
附圖.11	Mass spectrum of M3-----	95
附圖.12	Mass spectrum of M4-----	96
附圖.13	(a)TGA (b)DSC thermogram of P1-----	97
附圖.14	(a)TGA (b)DSC thermogram of P2-----	98
附圖.15	(a)TGA (b)DSC thermogram of P3-----	99
附圖.16	(a)TGA (b)DSC thermogram of P4-----	100